

74AUP1G58GXZ Datasheet



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DiGi Electronics Part Number 74AUP1G58GXZ-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number 74AUP1G58GXZ

Description IC GATE CONFIG MULTI-FUNC X2SON6

Detailed Description Configurable Multiple Function Configurable 1 Circ

uit 3 Input 6-X2SON (1.0x0.8)



Tel: +00 852-30501935

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Manufacturer Product Number:	Manufacturer:
74AUP1G58GXZ	Nexperia USA Inc.
Series:	Product Status:
74AUP	Active
Logic Type:	Number of Circuits:
Configurable Multiple Function	1
Number of Inputs:	Schmitt Trigger Input:
3	No
Output Type:	Current - Output High, Low:
Output Type: Single-Ended	Current - Output High, Low: 4mA, 4mA
Single-Ended	4mA, 4mA
Single-Ended Voltage - Supply:	4mA, 4mA Operating Temperature:
Single-Ended Voltage - Supply: 0.8V ~ 3.6V	4mA, 4mA Operating Temperature: -40°C ~ 125°C
Single-Ended Voltage - Supply: 0.8V ~ 3.6V Mounting Type:	4mA, 4mA Operating Temperature: -40°C ~ 125°C Package / Case:

Environmental & Export classification

8542.39.0001

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

74AUP1G58

Low-power configurable multiple function gate

Rev. 10 — 24 July 2023

Product data sheet

1. General description

The 74AUP1G58 is a configurable multiple function gate with Schmitt-trigger inputs. The device can be configured as any of the following logic functions AND, OR, NAND, NOR, XOR, inverter and buffer; using the 3-bit input. All inputs can be connected directly to V_{CC} or GND. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · CMOS low power dissipation
- High noise immunity
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- · Latch-up performance exceeds 100 mA per JESD 78 Class II
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Ordering information

Table 1. Ordering information

Type number	Package					
	Temperature range	Name	Description	Version		
74AUP1G58GW	-40 °C to +125 °C	TSSOP6	plastic thin shrink small outline package; 6 leads; body width 1.25 mm	SOT363-2		
74AUP1G58GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886		
74AUP1G58GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	<u>SOT1115</u>		
74AUP1G58GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	SOT1202		
74AUP1G58GX	-40 °C to +125 °C	X2SON6	plastic thermal enhanced extremely thin small outline package; no leads; 6 terminals; body 1.0 × 0.8 × 0.32 mm	SOT1255-2		



Low-power configurable multiple function gate

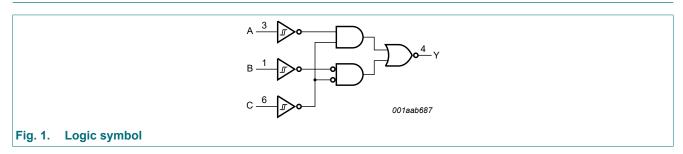
4. Marking

Table 2. Marking

Type number	Marking code [1]
74AUP1G58GW	аК
74AUP1G58GM	аК
74AUP1G58GN	аК
74AUP1G58GS	аК
74AUP1G58GX	аК

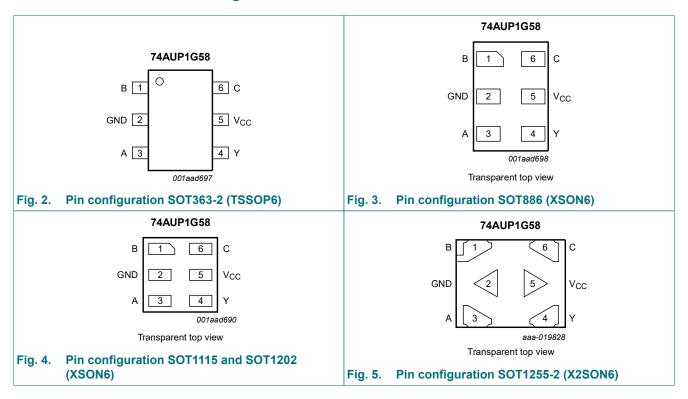
^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1. Pinning



Low-power configurable multiple function gate

6.2. Pin description

Table 3. Pin description

Symbol	Pin	Description
В	1	data input
GND	2	ground (0 V)
A	3	data input
Υ	4	data output
V _{CC}	5	supply voltage
С	6	data input

7. Functional description

Table 4. Function table

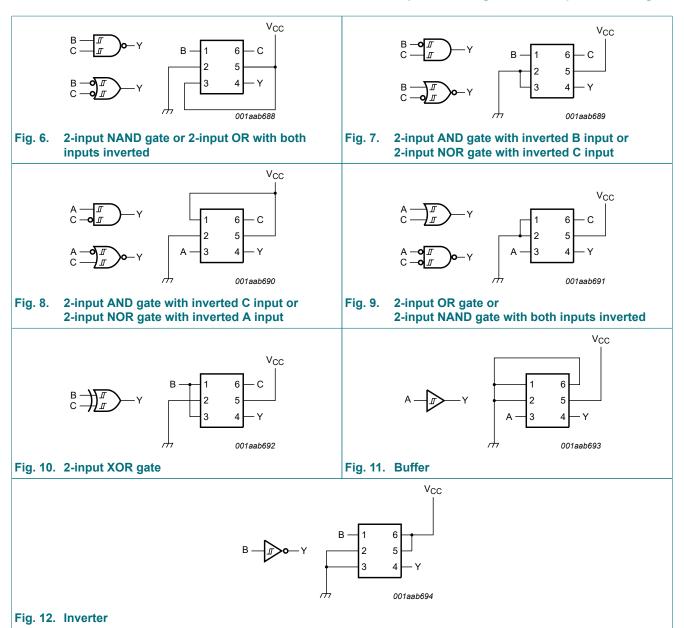
 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$

Input			Output
С	В	A	Υ
L	L	L	L
L	L	Н	Н
L	Н	L	L
L	Н	Н	Н
Н	L	L	Н
Н	L	Н	Н
Н	Н	L	L
Н	Н	Н	L

7.1. Logic configurations

Table 5. Function selection table

Logic function	Figure
2-input NAND	see Fig. 6
2-input NAND with both inputs inverted	see Fig. 9
2-input AND with inverted input	see Fig. 7 and Fig. 8
2-input NOR with inverted input	see Fig. 7 and Fig. 8
2-input OR	see Fig. 9
2-input OR with both inputs inverted	see Fig. 6
2-input XOR	see Fig. 10
Buffer	see Fig. 11
Inverter	see Fig. 12



Low-power configurable multiple function gate

8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}$ [2]	-	250	mW

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

For SOT886 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: Ptot derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1255-2 (X2SON6) package: P_{tot} derates linearly with 3.3 mW/K above 75 °C.

9. Recommended operating conditions

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

^[2] For SOT363-2 (TSSOP6) package: Ptot derates linearly with 3.7 mW/K above 83 °C.

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10. Static characteristics

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C		_		'	
V _{OH}	HIGH-level output	$V_I = V_{T+}$ or V_{T-}				
	voltage	I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I_{O} = -2.3 mA; V_{CC} = 2.3 V	2.05	-	-	V
		I_{O} = -3.1 mA; V_{CC} = 2.3 V	1.9	-	-	V
		I_{O} = -2.7 mA; V_{CC} = 3.0 V	2.72	-	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output	$V_I = V_{T+}$ or V_{T-}				
	voltage	I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.1	μΑ
l _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.2	μΑ
Δl _{OFF}	additional power-off leakage current	V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.2	μΑ
I _{CC}	supply current	V_{I} = GND or V_{CC} ; I_{O} = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI _{CC}	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	40	μΑ
Cı	input capacitance	V_I = GND or V_{CC} ; V_{CC} = 0 V to 3.6 V	-	1.1	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.8	-	pF

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74AUP1G58

V _{CC} - 0.1 0.7 × V _{CC} 1.03 1.30 1.97 1.85	- - - -	- - -	V V
0.7 × V _{CC} 1.03 1.30 1.97	- -	- - -	V
0.7 × V _{CC} 1.03 1.30 1.97	- -	- - -	V
1.03 1.30 1.97	-	-	
1.30 1.97		-	V
1.97		-	
	-	1	V
1.85		-	V
	-	-	V
2.67	-	-	V
2.55	-	-	V
-	-	0.1	V
-	-	0.3 × V _{CC}	V
-	-	0.37	V
-	-	0.35	V
-	-	0.33	V
-	-	0.45	V
-	-	0.33	V
-	-	0.45	V
-	-	±0.5	μΑ
-	-	±0.5	μA
-	-	±0.6	μΑ
3.6 V -	-	0.9	μΑ
-	-	50	μA
	2.55	2.55 -	2.55 0.1 - 0.3 × V _{CC} 0.37 0.35 0.35 0.45 0.45 0.45 ±0.5 ±0.5

Low-power configurable multiple function gate

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +125 °C					
V _{OH}	HIGH-level output	$V_I = V_{T+}$ or V_{T-}				
	voltage	I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I_{O} = -4.0 mA; V_{CC} = 3.0 V	2.30	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = 20 μ A; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		$I_O = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
l _l	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	μΑ
l _{OFF}	power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μΑ
Δl _{OFF}	additional power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V	-	-	±0.75	μΑ
I _{CC}	supply current	V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	1.4	μΑ
ΔI _{CC}	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$	-	-	75	μΑ

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 14.

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
$C_L = 5 p$	F									
t _{pd}	propagation delay	A, B and C to Y; see <u>Fig. 13</u> [2]								
		V _{CC} = 0.8 V	-	22.8	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	6.6	12.9	2.6	13.1	2.6	13.3	ns
		V _{CC} = 1.4 V to 1.6 V	2.4	4.8	7.6	2.4	8.3	2.4	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	4.0	6.3	2.0	6.9	2.0	7.3	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.2	4.6	1.8	5.1	1.8	5.4	ns
		V _{CC} = 3.0 V to 3.6 V	1.9	2.9	3.9	1.6	4.2	1.6	4.4	ns

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C _L = 10 դ	propagation delay	A, B and C to Y; see Fig. 13 [2] $V_{CC} = 0.8 \text{ V}$ $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	Min - 3.2	Typ [1] 26.4	Max	Min	Max	Min	Max	
	propagation	V _{CC} = 0.8 V V _{CC} = 1.1 V to 1.3 V	-	26.4						
t _{pd}		V _{CC} = 0.8 V V _{CC} = 1.1 V to 1.3 V	-	26.4						
	delay	V _{CC} = 1.1 V to 1.3 V		26.4						
			3.2	20.4	-	-	-	-	-	ns
		V _{CC} = 1.4 V to 1.6 V	1	7.4	14.5	3.0	14.9	3.0	15.2	ns
			2.7	5.4	8.7	2.7	9.4	2.7	9.8	ns
		V _{CC} = 1.65 V to 1.95 V	2.5	4.5	7.1	2.3	7.9	2.3	8.3	ns
		V _{CC} = 2.3 V to 2.7 V		3.8	5.3	2.2	5.9	2.2	6.2	ns
		V _{CC} = 3.0 V to 3.6 V	2.3	3.5	4.6	1.9	4.9	1.9	5.1	ns
C _L = 15 p	ρF		'	1		•				
t _{pd}	propagation	A, B and C to Y; see <u>Fig. 13</u> [2]								
	delay	V _{CC} = 0.8 V	-	29.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	8.3	16.1	3.3	16.7	3.3	17.0	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.9	9.7	3.0	10.5	3.0	11.0	ns
		V _{CC} = 1.65 V to 1.95 V	2.8	5.0	7.9	2.5	8.7	2.5	9.2	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.2	5.9	2.5	6.6	2.5	6.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.5	3.9	5.2	2.2	5.5	2.2	5.8	ns
C _L = 30 p	pF		•							
t _{pd}	propagation	A, B and C to Y; see <u>Fig. 13</u> [2]								
	delay	V _{CC} = 0.8 V	-	38.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.5	10.5	20.8	4.1	21.9	4.1	24.1	ns
		V _{CC} = 1.4 V to 1.6 V	3.8	7.5	12.2	3.8	13.5	3.8	14.1	ns
		V _{CC} = 1.65 V to 1.95 V	3.4	6.3	10.0	3.1	11.2	3.1	11.9	ns
		V _{CC} = 2.3 V to 2.7 V	3.4	5.3	7.5	3.1	8.4	3.1	8.9	ns
		V _{CC} = 3.0 V to 3.6 V	3.3	5.0	6.6	2.9	7.1	2.9	7.4	ns
C _L = 5 pl	F, 10 pF, 15 pF	and 30 pF	'				'			
C _{PD}	power	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3][4]								
	dissipation capacitance	V _{CC} = 0.8 V	-	2.7	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.2	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.8	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.4	-	-	-	-	-	pF

All typical values are measured at nominal V_{CC}.

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma (C_L \times V_{CC}^{\ 2} \times f_o) = \text{sum of the outputs}.$

^[2]

 t_{pd} is the same as t_{PLH} and t_{PHL} . All specified values are the average typical values over all stated loads.

^[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

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11.1. Waveforms and test circuit

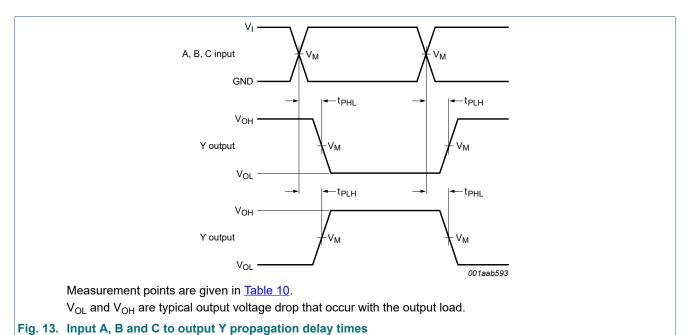
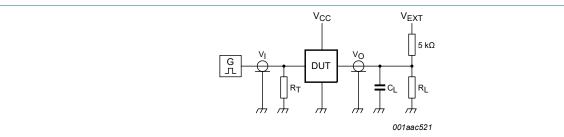


Table 10. Measurement points							
Supply voltage Output Input							
V _{CC}	V _M	V _M	VI	$t_r = t_f$			
0.8 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns			



Test data is given in Table 11.

Definitions for test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator;

V_{EXT} = External voltage for measuring switching times.

Fig. 14. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load		V _{EXT}				
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}		
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}		

^[1] For measuring enable and disable times R_L = 5 k Ω .

For measuring propagation delays, setup and hold times and pulse width R_L = 1 $M\Omega$.

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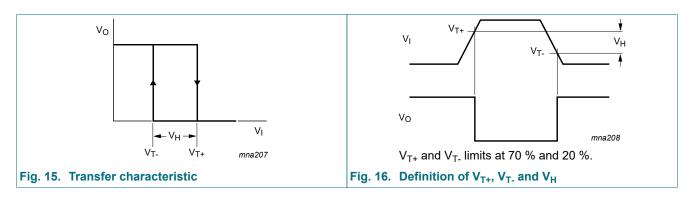
12. Transfer characteristics

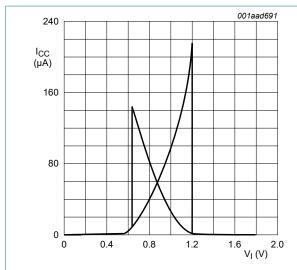
Table 12. Transfer characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 14.

Symbol	Parameter	Conditions		25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V _{T+}	positive-going	see Fig. 15 and Fig. 16								
	threshold voltage	V _{CC} = 0.8 V	0.30	-	0.60	0.30	0.60	0.30	0.62	V
	Voltage	V _{CC} = 1.1 V	0.53	-	0.90	0.53	0.90	0.53	0.92	V
		V _{CC} = 1.4 V	0.74	-	1.11	0.74	1.11	0.74	1.13	V
		V _{CC} = 1.65 V	0.91	-	1.29	0.91	1.29	0.91	1.31	V
		V _{CC} = 2.3 V	1.37	-	1.77	1.37	1.77	1.37	1.80	V
		V _{CC} = 3.0 V	1.88	-	2.29	1.88	2.29	1.88	2.32	V
V _{T-}	negative-going threshold voltage	see Fig. 15 and Fig. 16								
		V _{CC} = 0.8 V	0.10	-	0.60	0.10	0.60	0.10	0.60	V
		V _{CC} = 1.1 V	0.26	-	0.65	0.26	0.65	0.26	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	0.39	0.75	0.39	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	0.47	0.84	0.47	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	0.69	1.04	0.69	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	0.88	1.24	0.88	1.24	V
V _H	hysteresis voltage	(V _{T+} - V _{T-}); see <u>Fig. 15</u> , <u>Fig. 16</u> , <u>Fig. 17</u> and <u>Fig. 18</u>								
		V _{CC} = 0.8 V	0.07	-	0.50	0.07	0.50	0.07	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	0.08	0.46	0.08	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	0.18	0.56	0.18	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	0.27	0.66	0.27	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	0.53	0.92	0.53	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	0.79	1.31	0.79	1.31	V

12.1. Waveforms transfer characteristics







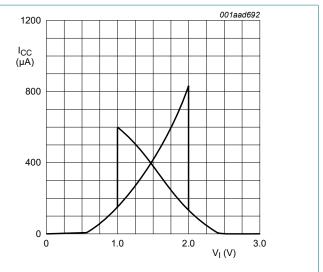


Fig. 18. Typical transfer characteristics; V_{CC} = 3.0 V

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13. Package outline

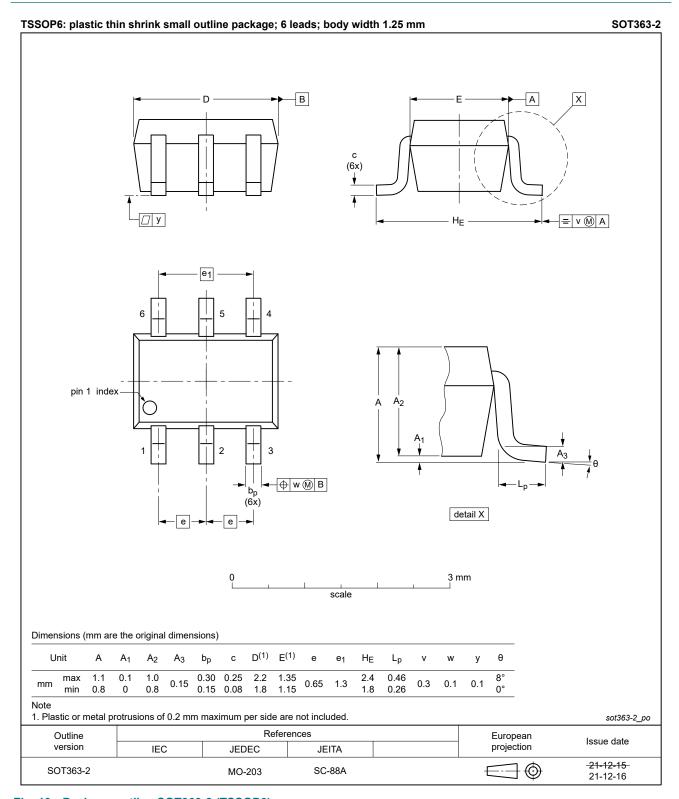


Fig. 19. Package outline SOT363-2 (TSSOP6)

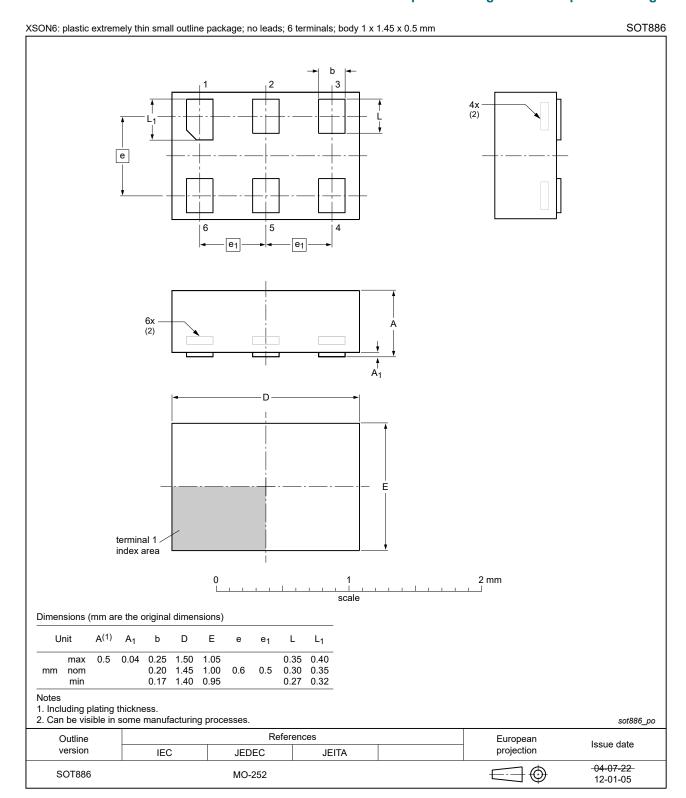


Fig. 20. Package outline SOT886 (XSON6)

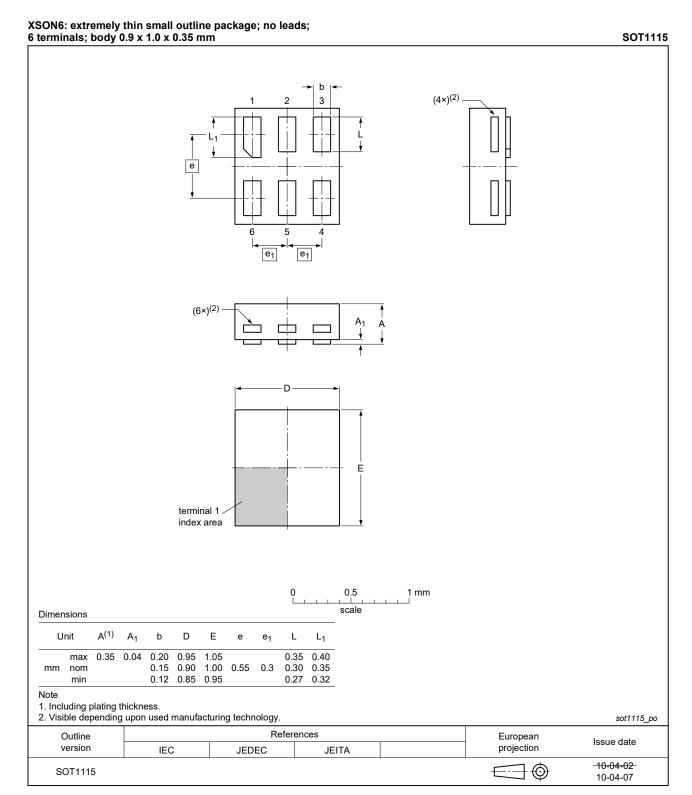


Fig. 21. Package outline SOT1115 (XSON6)

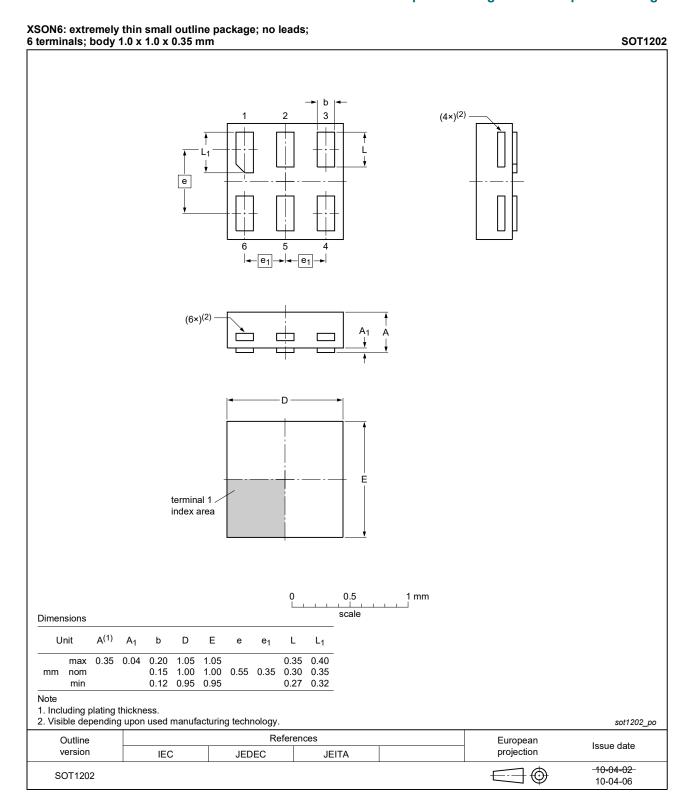


Fig. 22. Package outline SOT1202 (XSON6)

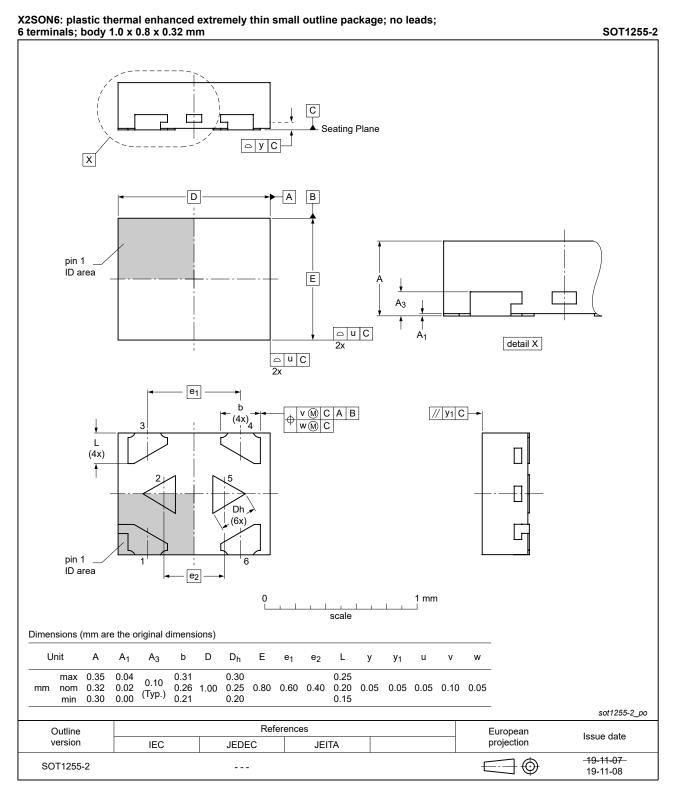


Fig. 23. Package outline SOT1255-2 (X2SON6)

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14. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model

15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AUP1G58 v.10	20230724	Product data sheet	-	74AUP1G58 v.9			
Modifications:	Section 2: E	ESD specification updated	according to the la	atest JEDEC standard.			
74AUP1G58 v.9	20220124	0220124 Product data sheet - 74AUP1G58 v.8					
Modifications:	• SOT363 (S	SOT363 (SC-88) package changed to SOT363-2 (TSSOP6) package.					
74AUP1G58 v.8	20210713	Product data sheet	-	74AUP1G58 v.7			
Modifications:	guidelines of Legal texts SOT1255 (Type number Section 1 a	Legal texts have been adapted to the new company harne where appropriate.					
74AUP1G58 v.7	20150917	Product data sheet	-	74AUP1G58 v.6			
Modifications:	Added type	number 74AUP1G58GX	(SOT1255/X2SON	6).			
74AUP1G58 v.6	20120815	Product data sheet	-	74AUP1G58 v.5			
Modifications:	• Package ou	ıtline drawing of SOT886	(Fig. 20) modified.				
74AUP1G58 v.5	20111129	Product data sheet	-	74AUP1G58 v.4			
74AUP1G58 v.4	20101011	Product data sheet	-	74AUP1G58 v.3			
74AUP1G58 v.3	20090622	Product data sheet	-	74AUP1G58 v.2			
74AUP1G58 v.2	20090326	Product data sheet	-	74AUP1G58 v.1			
74AUP1G58 v.1	20070131	Product data sheet	-	-			

16. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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